

**600mA CMOS LDO REGULATOR WITH ENABLE**
**AP2111**

### General Description

The AP2111 is CMOS process low dropout linear regulator with enable function, the regulator delivers a guaranteed 600mA (Min) continuous load current.

The AP2111 provides 1.2V, 1.5V, 1.8V, 2.5V, 3.3V, 4.8V regulated output and 0.8V to 5V adjustable output, and provides excellent output accuracy 1.5%, it is also provides a excellent load regulation, line regulation and excellent load transient performance due to very fast loop response. The AP2111 has built-in auto discharge function.

The AP2111 features low power consumption.

The AP2111 is available in SOIC-8, PSOP-8 SOT-223 and SOT-23-5 packages.

### Features

- Output Voltage Accuracy:  $\pm 1.5\%$
- Output Current: 600mA (Min)
- Foldback Short Current Protection: 50mA
- Enable Function to Turn On/Off  $V_{OUT}$
- Low Dropout Voltage (3.3V): 250mV (Typ) @  $I_{OUT}=600mA$
- Excellent Load Regulation: 0.2%/A (Typ)
- Excellent Line Regulation: 0.02%/V (Typ)
- Low Quiescent Current: 55 $\mu A$  (Typ)
- Low Standby Current: 0.01 $\mu A$  (Typ)
- Low Output Noise: 50 $\mu V_{RMS}$
- PSRR: 65dB @  $f=1kHz$ , 65dB @  $f=100Hz$
- OTSD Protection
- Stable with 1.0 $\mu F$  Flexible Cap: Ceramic, Tantalum and Aluminum Electrolytic
- Operating Temperature Range:  $-40^{\circ}C$  to  $85^{\circ}C$
- ESD: MM 400V, HBM 4000V

### Applications

- Laptop computer
- Potable DVD
- LCD Monitor

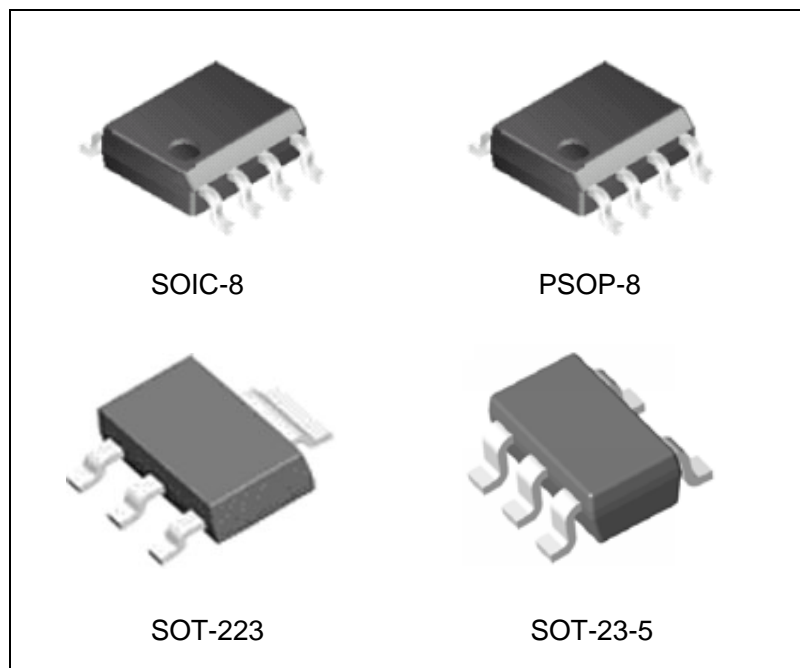


Figure 1. Package Types of AP2111

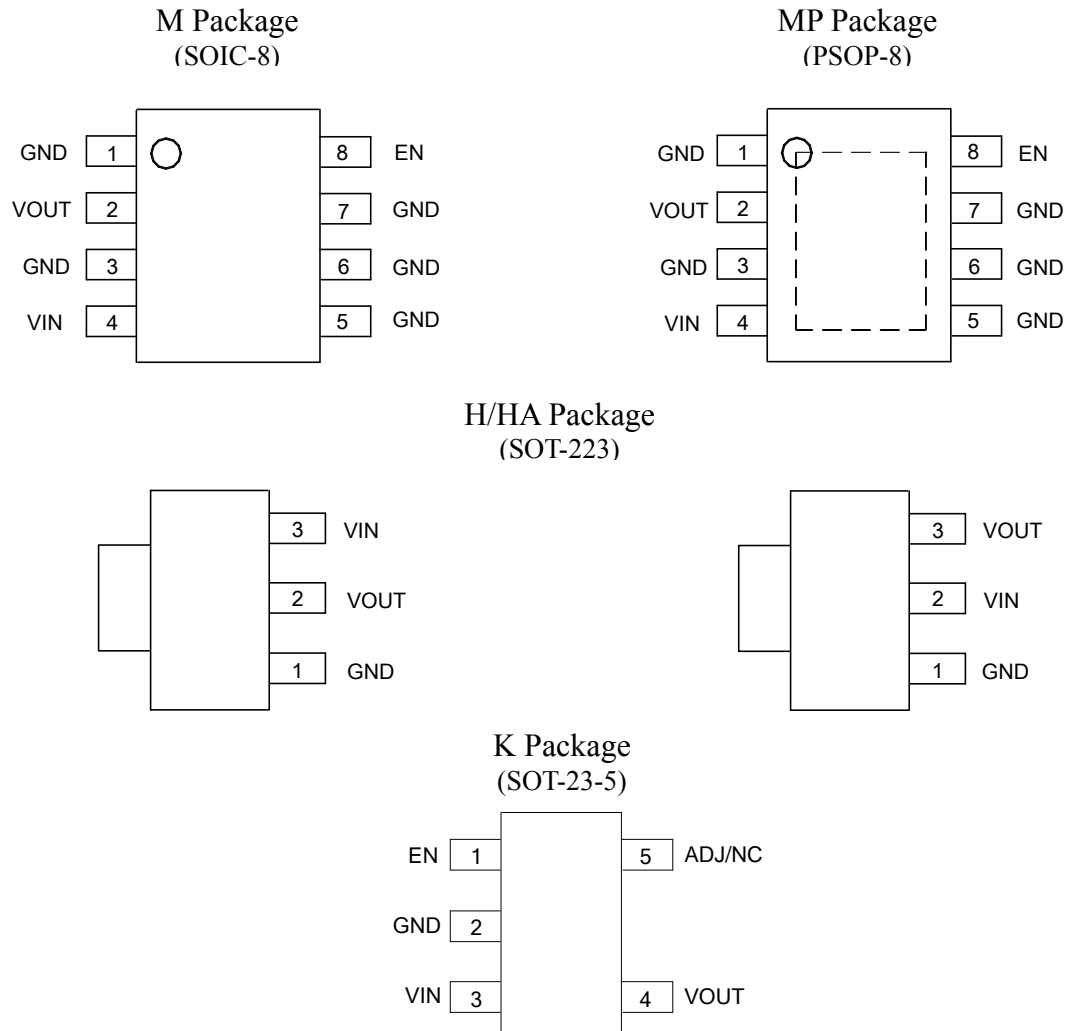
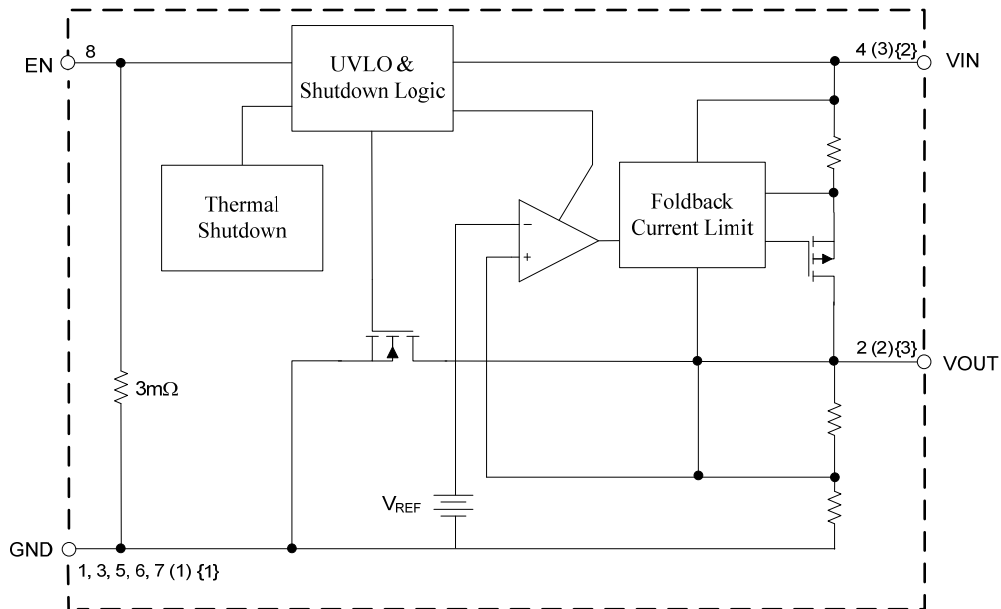
**600mA CMOS LDO REGULATOR WITH ENABLE**
**AP2111**
**Pin Configuration**


Figure 2. Pin Configuration of AP2111 (Top View)

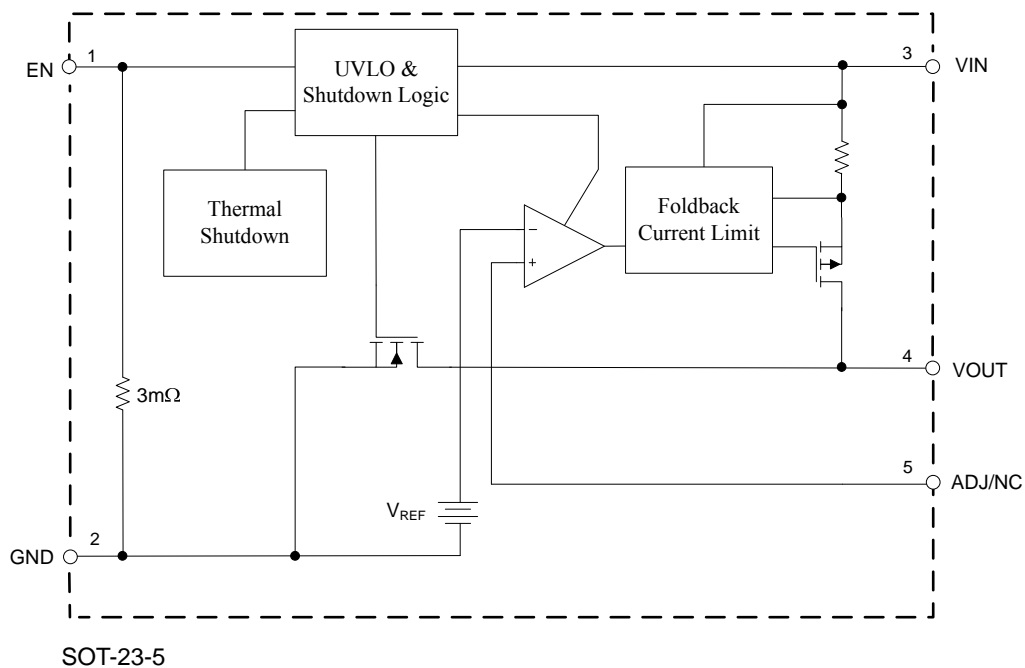
**Pin Descriptions**

Pin Number				Pin Name	Function
SOIC-8/PSOP-8	SOT-223(H)	SOT-223(HA)	SOT-23-5		
4	3	2	3	VIN	Input voltage
2	2	3	4	VOUT	Output voltage
8			1	EN	Chip enable, H – normal work, L – shutdown output
1, 3, 5, 6, 7	1	1	2	GND	Ground
			5	ADJ/NC	Adjust output for ADJ version/No connected for fixed version

**600mA CMOS LDO REGULATOR WITH ENABLE**
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**Functional Block Diagram**


A (B) (C)  
 A: SOIC-8/PSOP-8  
 B: SOT-223(H)  
 C: SOT-223(HA)

Figure 3. Functional Block Diagram of AP2111 for Fixed Version



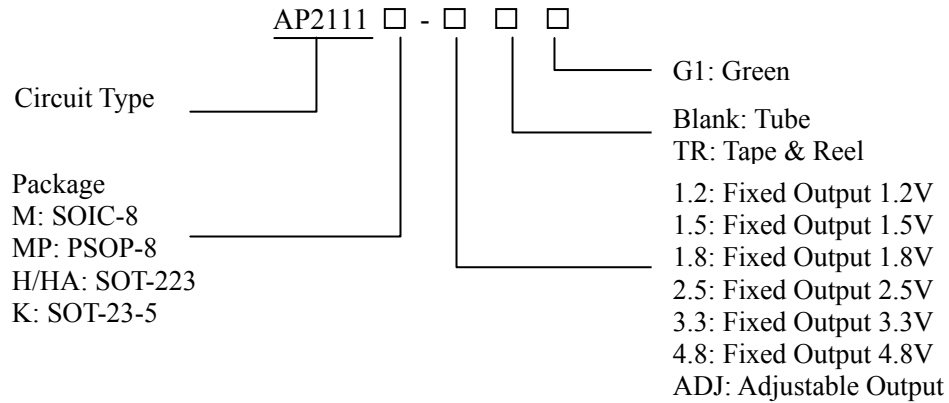
SOT-23-5

Figure 4. Functional Block Diagram of AP2111 for Adjustable Version

**600mA CMOS LDO REGULATOR WITH ENABLE**

**AP2111**

**Ordering Information**



Package	Temperature Range	Part Number	Marking ID	Packing Type
SOIC-8	-40 to 85°C	AP2111M-1.2G1	2111M-1.2G1	Tube
		AP2111M-1.2TRG1	2111M-1.2G1	Tape & Reel
		AP2111M-1.5G1	2111M-1.5G1	Tube
		AP2111M-1.5TRG1	2111M-1.5G1	Tape & Reel
		AP2111M-1.8G1	2111M-1.8G1	Tube
		AP2111M-1.8TRG1	2111M-1.8G1	Tape & Reel
		AP2111M-2.5G1	2111M-2.5G1	Tube
		AP2111M-2.5TRG1	2111M-2.5G1	Tape & Reel
		AP2111M-3.3G1	2111M-3.3G1	Tube
		AP2111M-3.3TRG1	2111M-3.3G1	Tape & Reel
PSOP-8	-40 to 85°C	AP2111MP-1.2G1	2111MP-1.2G1	Tube
		AP2111MP-1.2TRG1	2111MP-1.2G1	Tape & Reel
		AP2111MP-1.5G1	2111MP-1.5G1	Tube
		AP2111MP-1.5TRG1	2111MP-1.5G1	Tape & Reel
		AP2111MP-1.8G1	2111MP-1.8G1	Tube
		AP2111MP-1.8TRG1	2111MP-1.8G1	Tape & Reel
		AP2111MP-2.5G1	2111MP-2.5G1	Tube
		AP2111MP-2.5TRG1	2111MP-2.5G1	Tape & Reel
		AP2111MP-3.3G1	2111MP-3.3G1	Tube
		AP2111MP-3.3TRG1	2111MP-3.3G1	Tape & Reel
SOT-223(H)	-40 to 85°C	AP2111H-1.2TRG1	GH11B	Tape & Reel
		AP2111H-1.5TRG1	GH13G	Tape & Reel
		AP2111H-1.8TRG1	GH11G	Tape & Reel
		AP2111H-2.5TRG1	GH11H	Tape & Reel
		AP2111H-3.3TRG1	GH11C	Tape & Reel
		AP2111H-4.8TRG1	GH13D	Tape & Reel

**600mA CMOS LDO REGULATOR WITH ENABLE****AP2111****Ordering Information (Continued)**

Package	Temperature Range	Part Number	Marking ID	Packing Type
SOT-223(HA)	-40 to 85°C	AP2111HA-1.2TRG1	GH11J	Tape & Reel
		AP2111HA-1.5TRG1	GH14G	Tape & Reel
		AP2111HA-1.8TRG1	GH11K	Tape & Reel
		AP2111HA-2.5TRG1	GH11L	Tape & Reel
		AP2111HA-3.3TRG1	GH11M	Tape & Reel
		AP2111HA-4.8TRG1	GH11N	Tape & Reel
SOT-23-5	-40 to 85°C	AP2111K-1.5TRG1	G3S	Tape & Reel
		AP2111K-ADJG1	G3Q	Tube
		AP2111K-ADJTRG1	G3Q	Tape & Reel

BCD Semiconductor's Pb-free products, as designated with "G1" suffix in the part number, are RoHS compliant and Green.

**600mA CMOS LDO REGULATOR WITH ENABLE****AP2111****Absolute Maximum Ratings (Note 1)**

Parameter	Symbol	Value		Unit
Power Supply Voltage	$V_{IN}$	6.5		V
Operating Junction Temperature Range	$T_J$	150		°C
Storage Temperature Range	$T_{STG}$	-65 to 150		°C
Lead Temperature (Soldering, 10sec)	$T_{LEAD}$	260		°C
Thermal Resistance (No Heatsink)	$\theta_{JA}$	SOIC-8	144	°C/W
		PSOP-8	143	
		SOT-223	128	
		SOT-23-5	250	
ESD (Machine Model)		400		V
ESD (Human Body Model)		4000		V

Note 1: Stresses greater than those listed under “Absolute Maximum Ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “Recommended Operating Conditions” is not implied. Exposure to “Absolute Maximum Ratings” for extended periods may affect device reliability.

**Recommended Operating Conditions**

Parameter	Symbol	Min	Typ	Max	Unit
Supply Voltage	$V_{IN}$	2.5		6.0	V
Operating Ambient Temperature Range	$T_A$	-40		85	°C



**600mA CMOS LDO REGULATOR WITH ENABLE**

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**Electrical Characteristics**

**AP2111-1.2 Electrical Characteristic (Note 2)**

V<sub>IN</sub>=2.5V, C<sub>IN</sub>=1.0μF (Ceramic), C<sub>OUT</sub>=1.0μF (Ceramic), Typical T<sub>A</sub>=25°C, **Bold** typeface applies over -40°C≤T<sub>A</sub>≤85°C ranges, unless otherwise specified (Note 3).

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Output Voltage	V <sub>OUT</sub>	V <sub>IN</sub> =2.5V, 1mA ≤ I <sub>OUT</sub> ≤ 30mA	$\frac{V_{OUT}}{\times 98.5\%}$	1.2	$\frac{V_{OUT}}{\times 101.5\%}$	V
Maximum Output Current	I <sub>OUT(Max)</sub>	V <sub>IN</sub> =2.5V, V <sub>OUT</sub> =1.182V to 1.218V	600			mA
Load Regulation	$\frac{(\Delta V_{OUT}/V_{OUT})}{\Delta I_{OUT}}$	V <sub>IN</sub> =2.5V, 1mA ≤ I <sub>OUT</sub> ≤ 600mA		0.2		%/A
Line Regulation	$\frac{(\Delta V_{OUT}/V_{OUT})}{\Delta V_{IN}}$	2.5V ≤ V <sub>IN</sub> ≤ 6V, I <sub>OUT</sub> =30mA		0.02		%/V
Dropout Voltage	V <sub>DROP</sub>	I <sub>OUT</sub> =10mA		1000	1300	mV
		I <sub>OUT</sub> =300mA		1000	1300	
		I <sub>OUT</sub> =600mA		1000	1300	
Quiescent Current	I <sub>Q</sub>	V <sub>IN</sub> =2.5V, I <sub>OUT</sub> =0mA		55	80	μA
Standby Current	I <sub>STD</sub>	V <sub>IN</sub> =2.5V, V <sub>EN</sub> in OFF mode		0.01	1.0	μA
Power Supply Rejection Ratio	PSRR	Ripple 0.5Vp-p V <sub>IN</sub> =2.5V, I <sub>OUT</sub> =100mA	f=100Hz	65		dB
			f=1kHz	65		
Output Voltage Temperature Coefficient	$\frac{(\Delta V_{OUT}/V_{OUT})}{\Delta T}$	I <sub>OUT</sub> =30mA T <sub>A</sub> =-40°C to 85°C		<b>±100</b>		ppm/°C
Short Current Limit	I <sub>SHORT</sub>	V <sub>OUT</sub> =0V		50		mA
RMS Output Noise	V <sub>NOISE</sub>	No Load, 10Hz ≤ f ≤ 100kHz		50		μV <sub>RMS</sub>
VEN High Voltage	V <sub>IH</sub>	Enable logic high, regulator on	1.5		6.0	V
VEN Low Voltage	V <sub>IL</sub>	Enable logic low, regulator off	0		0.4	
Start-up Time	t <sub>S</sub>	No Load		20		μs
EN Pull Down Resistor	R <sub>PD</sub>			3.0		mΩ
V <sub>OUT</sub> Discharge Resistor	R <sub>DCHG</sub>	Set EN pin at Low		60		Ω
Thermal Shutdown Temperature	T <sub>OTSD</sub>			160		°C
Thermal Shutdown Hysteresis	T <sub>HYOTSD</sub>			30		
Thermal Resistance (Junction to Case)	θ <sub>JC</sub>	SOIC-8		74.6		°C/W
		PSOP-8		43.7		
		SOT-223		50.9		

Note 2: To prevent the Short Circuit Current protection feature from being prematurely activated, the input voltage must be applied before a current source load is applied.

Note 3: Production testing at T<sub>A</sub>=25°C. Over temperature specifications guaranteed by design only.

**600mA CMOS LDO REGULATOR WITH ENABLE****AP2111****Electrical Characteristics (Continued)****AP2111-1.5 Electrical Characteristic (Note 2)**

$V_{IN}=2.5V$ ,  $C_{IN}=1.0\mu F$  (Ceramic),  $C_{OUT}=1.0\mu F$  (Ceramic), Typical  $T_A=25^\circ C$ , **Bold** typeface applies over  $-40^\circ C \leq T_A \leq 85^\circ C$  ranges, unless otherwise specified (Note 3).

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Output Voltage	$V_{OUT}$	$V_{IN}=2.5V$ , $1mA \leq I_{OUT} \leq 30mA$	$\frac{V_{OUT}}{\times 98.5\%}$	1.5	$\frac{V_{OUT}}{\times 101.5\%}$	V
Maximum Output Current	$I_{OUT(Max)}$	$V_{IN}=2.5V$ , $V_{OUT}=1.478V$ to $1.523V$	600			mA
Load Regulation	$\frac{(\Delta V_{OUT}/V_{OUT})}{\Delta I_{OUT}}$	$V_{IN}=2.5V$ , $1mA \leq I_{OUT} \leq 600mA$		0.2		%/A
Line Regulation	$\frac{(\Delta V_{OUT}/V_{OUT})}{\Delta V_{IN}}$	$2.5V \leq V_{IN} \leq 6V$ , $I_{OUT}=30mA$		0.02		%/V
Dropout Voltage	$V_{DROP}$	$I_{OUT}=10mA$		700	1000	mV
		$I_{OUT}=300mA$		700	1000	
		$I_{OUT}=600mA$		700	1000	
Quiescent Current	$I_Q$	$V_{IN}=2.5V$ , $I_{OUT}=0mA$		55	80	$\mu A$
Standby Current	$I_{STD}$	$V_{IN}=2.5V$ , $V_{EN}$ in OFF mode		0.01	1.0	$\mu A$
Power Supply Rejection Ratio	PSRR	Ripple 0.5Vp-p $V_{IN}=2.5V$ , $I_{OUT}=100mA$	$f=100Hz$	65		dB
			$f=1kHz$	65		
Output Voltage Temperature Coefficient	$\frac{(\Delta V_{OUT}/V_{OUT})}{\Delta T}$	$I_{OUT}=30mA$ $T_A=-40^\circ C$ to $85^\circ C$		<b><math>\pm 100</math></b>		ppm/ $^\circ C$
Short Current Limit	$I_{SHORT}$	$V_{OUT}=0V$		50		mA
RMS Output Noise	$V_{NOISE}$	No Load, $10Hz \leq f \leq 100kHz$		50		$\mu V_{RMS}$
VEN High Voltage	$V_{IH}$	Enable logic high, regulator on	1.5		6.0	V
VEN Low Voltage	$V_{IL}$	Enable logic low, regulator off	0		0.4	
Start-up Time	$t_S$	No Load		20		$\mu s$
EN Pull Down Resistor	$R_{PD}$			3.0		m $\Omega$
VOUT Discharge Resistor	$R_{DCHG}$	Set EN pin at Low		60		$\Omega$
Thermal Shutdown Temperature	$T_{OTSD}$			160		$^\circ C$
Thermal Shutdown Hysteresis	$T_{HYOTSD}$			30		
Thermal Resistance (Junction to Case)	$\theta_{JC}$	SOIC-8		74.6		$^\circ C/W$
		PSOP-8		43.7		
		SOT-223		50.9		
		SOT-23-5		150		

Note 2: To prevent the Short Circuit Current protection feature from being prematurely activated, the input voltage must be applied before a current source load is applied.

Note 3: Production testing at  $T_A=25^\circ C$ . Over temperature specifications guaranteed by design only.



**600mA CMOS LDO REGULATOR WITH ENABLE****AP2111****Electrical Characteristics (Continued)****AP2111-1.8 Electrical Characteristic (Note 2)**

$V_{IN}=2.8V$ ,  $C_{IN}=1\mu F$  (Ceramic),  $C_{OUT}=1\mu F$  (Ceramic), Typical  $T_A=25^\circ C$ , **Bold** typeface applies over  $-40^\circ C \leq T_A \leq 85^\circ C$  ranges, unless otherwise specified (Note 3).

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Output Voltage	$V_{OUT}$	$V_{IN}=2.8V$ , $1mA \leq I_{OUT} \leq 30mA$	$\frac{V_{OUT}}{\times 98.5\%}$	1.8	$\frac{V_{OUT}}{\times 101.5\%}$	V
Maximum Output Current	$I_{OUT(Max)}$	$V_{IN}=2.8V$ , $V_{OUT}=1.773V$ to $1.827V$	600			mA
Load Regulation	$\frac{(\Delta V_{OUT}/V_{OUT})}{\Delta I_{OUT}}$	$V_{OUT}=1.8V$ , $V_{IN}=V_{OUT}+1V$ , $1mA \leq I_{OUT} \leq 600mA$		0.2		%/A
Line Regulation	$\frac{(\Delta V_{OUT}/V_{OUT})}{\Delta V_{IN}}$	$2.8V \leq V_{IN} \leq 6V$ , $I_{OUT}=30mA$		0.02		%/V
Dropout Voltage	$V_{DROP}$	$I_{OUT}=10mA$		500	700	mV
		$I_{OUT}=300mA$		500	700	
		$I_{OUT}=600mA$		500	700	
Quiescent Current	$I_Q$	$V_{IN}=2.8V$ , $I_{OUT}=0mA$		55	80	$\mu A$
Standby Current	$I_{STD}$	$V_{IN}=2.8V$ , $V_{EN}$ in OFF mode		0.01	1.0	$\mu A$
Power Supply Rejection Ratio	PSRR	Ripple 0.5Vp-p $V_{IN}=2.8V$ , $I_{OUT}=100mA$	$f=100Hz$		65	dB
			$f=1kHz$		65	
Output Voltage Temperature Coefficient	$\frac{(\Delta V_{OUT}/V_{OUT})}{\Delta T}$	$I_{OUT}=30mA$ $T_A=-40^\circ C$ to $85^\circ C$		<b><math>\pm 100</math></b>		ppm/ $^\circ C$
Short Current Limit	$I_{SHORT}$	$V_{OUT}=0V$		50		mA
RMS Output Noise	$V_{NOISE}$	No Load, $10Hz \leq f \leq 100kHz$		50		$\mu V_{RMS}$
VEN High Voltage	$V_{IH}$	Enable logic high, regulator on	1.5		6.0	V
VEN Low Voltage	$V_{IL}$	Enable logic low, regulator off	0		0.4	
Start-up Time	$t_s$	No Load		20		$\mu s$
EN Pull Down Resistor	$R_{PD}$			3.0		$m\Omega$
VOOUT Discharge Resistor	$R_{DCHG}$	Set EN pin at Low		60		$\Omega$
Thermal Shutdown Temperature	$T_{OTS D}$			160		$^\circ C$
Thermal Shutdown Hysteresis	$T_{HYOTS D}$			30		
Thermal Resistance (Junction to Case)	$\theta_{JC}$	SOIC-8		74.6		$^\circ C/W$
		PSOP-8		43.7		
		SOT-223		50.9		

Note 2: To prevent the Short Circuit Current protection feature from being prematurely activated, the input voltage must be applied before a current source load is applied.

Note 3: Production testing at  $T_A=25^\circ C$ . Over temperature specifications guaranteed by design only.



**600mA CMOS LDO REGULATOR WITH ENABLE**

**AP2111**

**Electrical Characteristics (Continued)**

**AP2111-2.5 Electrical Characteristic (Note 2)**

V<sub>IN</sub>=3.5V, C<sub>IN</sub>=1μF (Ceramic), C<sub>OUT</sub>=1μF (Ceramic), Typical T<sub>A</sub>=25°C, **Bold** typeface applies over -40°C≤T<sub>A</sub>≤85°C ranges, unless otherwise specified (Note 3).

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Output Voltage	V <sub>OUT</sub>	V <sub>IN</sub> =3.5V, 1mA ≤ I <sub>OUT</sub> ≤ 30mA	$\frac{V_{OUT}}{\times 98.5\%}$	2.5	$\frac{V_{OUT}}{\times 101.5\%}$	V
Maximum Output Current	I <sub>OUT(Max)</sub>	V <sub>IN</sub> =3.5V, V <sub>OUT</sub> =2.463V to 2.537V	600			mA
Load Regulation	$\frac{\Delta V_{OUT}/V_{OUT}}{\Delta I_{OUT}}$	V <sub>OUT</sub> =2.5V, V <sub>IN</sub> =V <sub>OUT</sub> +1V, 1mA ≤ I <sub>OUT</sub> ≤ 600mA		0.2		%/A
Line Regulation	$\frac{\Delta V_{OUT}/V_{OUT}}{\Delta V_{IN}}$	3.5V ≤ V <sub>IN</sub> ≤ 6V, I <sub>OUT</sub> =30mA		0.02		%/V
Dropout Voltage	V <sub>DROP</sub>	I <sub>OUT</sub> =10mA		5	8	mV
		I <sub>OUT</sub> =300mA		125	200	
		I <sub>OUT</sub> =600mA		250	400	
Quiescent Current	I <sub>Q</sub>	V <sub>IN</sub> =3.5V, I <sub>OUT</sub> =0mA		55	80	μA
Standby Current	I <sub>STD</sub>	V <sub>IN</sub> =3.5V, V <sub>EN</sub> in OFF mode		0.01	1.0	μA
Power Supply Rejection Ratio	PSRR	Ripple 0.5Vp-p V <sub>IN</sub> =3.5V, I <sub>OUT</sub> =100mA	f=100Hz	65		dB
			f=1kHz	65		
Output Voltage Temperature Coefficient	$\frac{\Delta V_{OUT}/V_{OUT}}{\Delta T}$	I <sub>OUT</sub> =30mA T <sub>A</sub> =-40°C to 85°C		<b>±100</b>		ppm/°C
Short Current Limit	I <sub>SHORT</sub>	V <sub>OUT</sub> =0V		50		mA
RMS Output Noise	V <sub>NOISE</sub>	No Load, 10Hz ≤ f ≤ 100kHz		50		μV <sub>RMS</sub>
VEN High Voltage	V <sub>IH</sub>	Enable logic high, regulator on	1.5		6.0	V
VEN Low Voltage	V <sub>IL</sub>	Enable logic low, regulator off	0		0.4	
Start-up Time	t <sub>S</sub>	No Load		20		μs
EN Pull Down Resistor	R <sub>PD</sub>			3.0		mΩ
VOU <sub>T</sub> Discharge Resistor	R <sub>DCHG</sub>	Set EN pin at Low		60		Ω
Thermal Shutdown Temperature	T <sub>OTSD</sub>			160		°C
Thermal Shutdown Hysteresis	T <sub>HYOTSD</sub>			30		
Thermal Resistance (Junction to Case)	θ <sub>JC</sub>	SOIC-8		74.6		°C/W
		PSOP-8		43.7		
		SOT-223		50.9		

Note 2: To prevent the short circuit current protection feature from being prematurely activated, the input voltage must be applied before a current source load is applied.

Note 3: Production testing at T<sub>A</sub>=25°C. Over temperature specifications guaranteed by design only.



**600mA CMOS LDO REGULATOR WITH ENABLE**

**AP2111**

**Electrical Characteristics (Continued)**

**AP2111-3.3 Electrical Characteristic (Note 2)**

V<sub>IN</sub>=4.3V, C<sub>IN</sub>=1μF (Ceramic), C<sub>OUT</sub>=1μF (Ceramic), Typical T<sub>A</sub>=25°C, **Bold** typeface applies over -40°C≤T<sub>A</sub>≤85°C ranges, unless otherwise specified (Note 3).

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Output Voltage	V <sub>OUT</sub>	V <sub>IN</sub> =4.3V, 1mA ≤ I <sub>OUT</sub> ≤ 30mA	$\frac{V_{OUT}}{\times 98.5\%}$	3.3	$\frac{V_{OUT}}{\times 101.5\%}$	V
Maximum Output Current	I <sub>OUT(Max)</sub>	V <sub>IN</sub> =4.3V, V <sub>OUT</sub> =3.251V to 3.350V	600			mA
Load Regulation	$\frac{(\Delta V_{OUT}/V_{OUT})}{\Delta I_{OUT}}$	V <sub>IN</sub> =4.3V, 1mA ≤ I <sub>OUT</sub> ≤ 600mA		0.2		%/A
Line Regulation	$\frac{(\Delta V_{OUT}/V_{OUT})}{\Delta V_{IN}}$	4.3V ≤ V <sub>IN</sub> ≤ 6V, I <sub>OUT</sub> =30mA		0.02		%/V
Dropout Voltage	V <sub>DROP</sub>	I <sub>OUT</sub> =10mA		5	8	mV
		I <sub>OUT</sub> =300mA		125	200	
		I <sub>OUT</sub> =600mA		250	400	
Quiescent Current	I <sub>Q</sub>	V <sub>IN</sub> =4.3V, I <sub>OUT</sub> =0mA		55	80	μA
Standby Current	I <sub>STD</sub>	V <sub>IN</sub> =4.3V, V <sub>EN</sub> in OFF mode		0.01	1.0	μA
Power Supply Rejection Ratio	PSRR	Ripple 0.5Vp-p V <sub>IN</sub> =4.3V, I <sub>OUT</sub> =100mA	f=100Hz	65		dB
			f=1kHz	65		
Output Voltage Temperature Coefficient	$\frac{(\Delta V_{OUT}/V_{OUT})}{\Delta T}$	I <sub>OUT</sub> =30mA T <sub>A</sub> =-40°C to 85°C		<b>±100</b>		ppm/°C
Short Current Limit	I <sub>SHORT</sub>	V <sub>OUT</sub> =0V		50		mA
RMS Output Noise	V <sub>NOISE</sub>	No Load, 10Hz ≤ f ≤ 100kHz		50		μV <sub>RMS</sub>
VEN High Voltage	V <sub>IH</sub>	Enable logic high, regulator on	1.5		6.0	V
VEN Low Voltage	V <sub>IL</sub>	Enable logic low, regulator off	0		0.4	
Start-up Time	t <sub>S</sub>	No Load		20		μs
EN Pull Down Resistor	R <sub>PD</sub>			3.0		mΩ
VOOUT Discharge Resistor	R <sub>DCHG</sub>	Set EN pin at Low		60		Ω
Thermal Shutdown Temperature	T <sub>OTSD</sub>			160		°C
Thermal Shutdown Hysteresis	T <sub>HYOTSD</sub>			30		
Thermal Resistance (Junction to Case)	θ <sub>JC</sub>	SOIC-8		74.6		°C/W
		PSOP-8		43.7		
		SOT-223		50.9		

Note 2: To prevent the short circuit current protection feature from being prematurely activated, the input voltage must be applied before a current source load is applied.

Note 3: Production testing at T<sub>A</sub>=25°C. Over temperature specifications guaranteed by design only.

**600mA CMOS LDO REGULATOR WITH ENABLE****AP2111****Electrical Characteristics (Continued)****AP2111-4.8 Electrical Characteristic (Note 2) (Only for SOT-223)**

$V_{IN}=5.5V$ ,  $C_{IN}=1\mu F$  (Ceramic),  $C_{OUT}=1\mu F$  (Ceramic), Typical  $T_A=25^\circ C$ , **Bold** typeface applies over  $-40^\circ C \leq T_A \leq 85^\circ C$  ranges, unless otherwise specified (Note 3).

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Output Voltage	$V_{OUT}$	$V_{IN}=5.5V$ , $1mA \leq I_{OUT} \leq 30mA$	$\frac{V_{OUT}}{\times 98.5\%}$	4.8	$\frac{V_{OUT}}{\times 101.5\%}$	V
Maximum Output Current	$I_{OUT(Max)}$	$V_{IN}=5.5V$ , $V_{OUT}=4.751V$ to $4.850V$	600			mA
Load Regulation	$\frac{(\Delta V_{OUT}/V_{OUT})}{\Delta I_{OUT}}$	$V_{IN}=5.5V$ , $1mA \leq I_{OUT} \leq 600mA$		0.2		%/A
Line Regulation	$\frac{(\Delta V_{OUT}/V_{OUT})}{\Delta V_{IN}}$	$5.5V \leq V_{IN} \leq 6V$ , $I_{OUT}=30mA$		0.02		%/V
Dropout Voltage	$V_{DROP}$	$I_{OUT}=10mA$		5	8	mV
		$I_{OUT}=300mA$		100	200	
		$I_{OUT}=600mA$		200	400	
Quiescent Current	$I_Q$	$V_{IN}=5.5V$ , $I_{OUT}=0mA$		55	80	$\mu A$
Standby Current	$I_{STD}$	$V_{IN}=5.5V$ , $V_{EN}$ in OFF mode		0.01	1.0	$\mu A$
Power Supply Rejection Ratio	PSRR	Ripple 0.5Vp-p $V_{IN}=5.5V$ , $I_{OUT}=100mA$	$f=100Hz$	65		dB
			$f=1kHz$	65		
Output Voltage Temperature Coefficient	$\frac{(\Delta V_{OUT}/V_{OUT})}{\Delta T}$	$I_{OUT}=30mA$ $T_A=-40^\circ C$ to $85^\circ C$		<b><math>\pm 100</math></b>		ppm/ $^\circ C$
Short Current Limit	$I_{SHORT}$	$V_{OUT}=0V$		50		mA
RMS Output Noise	$V_{NOISE}$	No Load, $10Hz \leq f \leq 100kHz$		50		$\mu V_{RMS}$
Thermal Shutdown Temperature	$T_{OTSD}$			160		$^\circ C$
Thermal Shutdown Hysteresis	$T_{HYOTSD}$			30		
Thermal Resistance (Junction to Case)	$\theta_{JC}$	SOT-223		50.9		

Note 2: To prevent the short circuit current protection feature from being prematurely activated, the input voltage must be applied before a current source load is applied.

Note 3: Production testing at  $T_A=25^\circ C$ . Over temperature specifications guaranteed by design only.

**600mA CMOS LDO REGULATOR WITH ENABLE**
**AP2111**
**Electrical Characteristics (Continued)**
**AP2111-ADJ Electrical Characteristic (Note 2) (Only for SOT-23-5)**

$V_{IN}=2.5V$ ,  $C_{IN}=1.0\mu F$  (Ceramic),  $C_{OUT}=1.0\mu F$  (Ceramic), Typical  $T_A=25^\circ C$ , **Bold** typeface applies over  $-40^\circ C \leq T_A \leq 85^\circ C$  ranges, unless otherwise specified (Note 3).

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Reference Voltage	$V_{REF}$	$V_{IN}=2.5V$ , $1mA \leq I_{OUT} \leq 30mA$	$\frac{V_{REF}}{\times 98.5\%}$	0.8	$\frac{V_{REF}}{\times 101.5\%}$	V
Maximum Output Current	$I_{OUT(Max)}$	$V_{IN}=2.5V$ , $V_{REF}=0.788V$ to $0.812V$	600			mA
Load Regulation	$\frac{(\Delta V_{OUT}/V_{OUT})}{\Delta I_{OUT}}$	$V_{IN}=2.5V$ , $1mA \leq I_{OUT} \leq 600mA$		0.2		%/A
Line Regulation	$\frac{(\Delta V_{OUT}/V_{OUT})}{\Delta V_{IN}}$	$2.5V \leq V_{IN} \leq 6V$ , $I_{OUT}=30mA$		0.02		%/V
Quiescent Current	$I_Q$	$V_{IN}=2.5V$ , $I_{OUT}=0mA$		55	80	$\mu A$
Standby Current	$I_{STD}$	$V_{IN}=2.5V$ , $V_{EN}$ in OFF mode		0.01	1.0	$\mu A$
Power Supply Rejection Ratio	PSRR	Ripple 0.5Vp-p $V_{IN}=2.5V$ , $I_{OUT}=100mA$	$f=100Hz$	65		dB
			$f=1kHz$	65		
Output Voltage Temperature Coefficient	$\frac{(\Delta V_{OUT}/V_{OUT})}{\Delta T}$	$I_{OUT}=30mA$ $T_A=-40^\circ C$ to $85^\circ C$		<b><math>\pm 100</math></b>		ppm/ $^\circ C$
Short Current Limit	$I_{SHORT}$	$V_{OUT}=0V$		50		mA
RMS Output Noise	$V_{NOISE}$	No Load, $10Hz \leq f \leq 100kHz$		50		$\mu V_{RMS}$
VEN High Voltage	$V_{IH}$	Enable logic high, regulator on	1.5		6.0	V
VEN Low Voltage	$V_{IL}$	Enable logic low, regulator off	0		0.4	
Start-up Time	$t_s$	No Load		20		$\mu s$
EN Pull Down Resistor	$R_{PD}$			3.0		m $\Omega$
VOUT Discharge Resistor	$R_{DCHG}$	Set EN pin at Low		60		$\Omega$
Thermal Shutdown Temperature	$T_{OTSD}$			160		$^\circ C$
Thermal Shutdown Hysteresis	$T_{HYOTSD}$			30		
Thermal Resistance (Junction to Case)	$\theta_{JC}$	SOT-23-5		150		$^\circ C/W$

Note 2: To prevent the Short Circuit Current protection feature from being prematurely activated, the input voltage must be applied before a current source load is applied.

Note 3: Production testing at  $T_A=25^\circ C$ . Over temperature specifications guaranteed by design only.

**Typical Performance Characteristics**

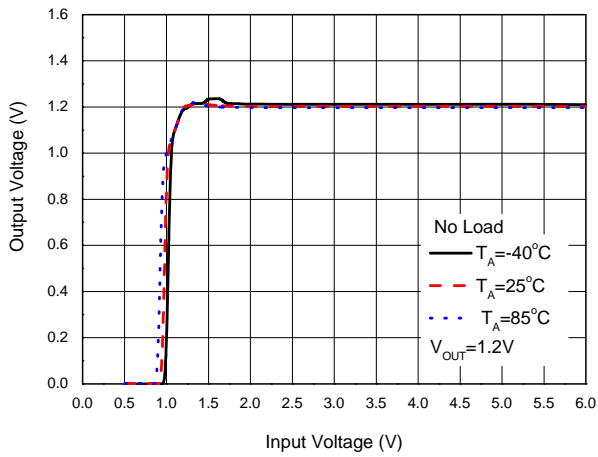


Figure 5. Output Voltage vs. Input Voltage

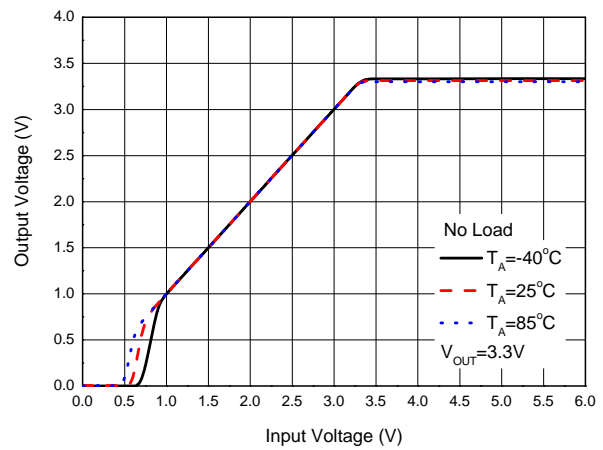


Figure 6. Output Voltage vs. Input Voltage

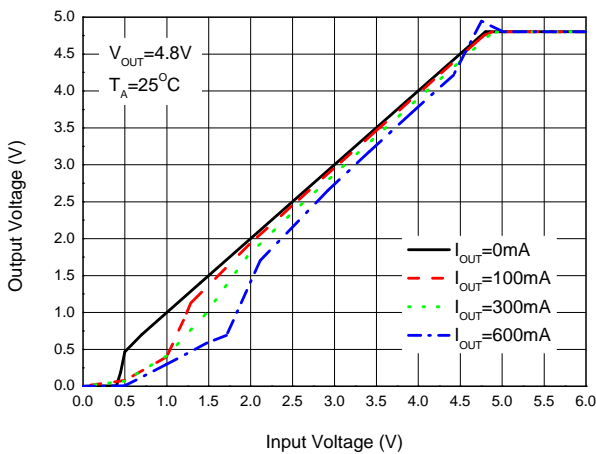


Figure 7. Output Voltage vs. Input Voltage

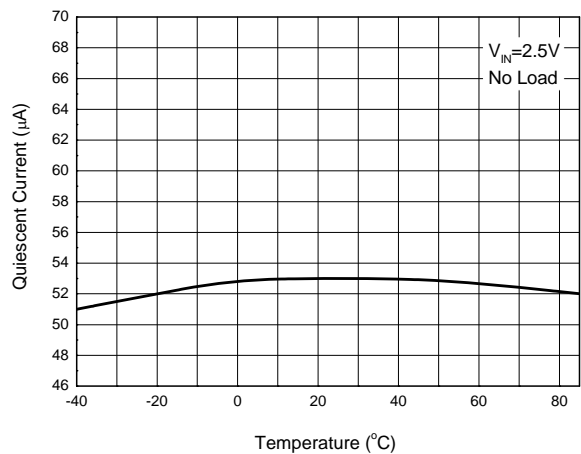


Figure 8. Quiescent Current vs. Temperature

**Typical Performance Characteristics (Continued)**

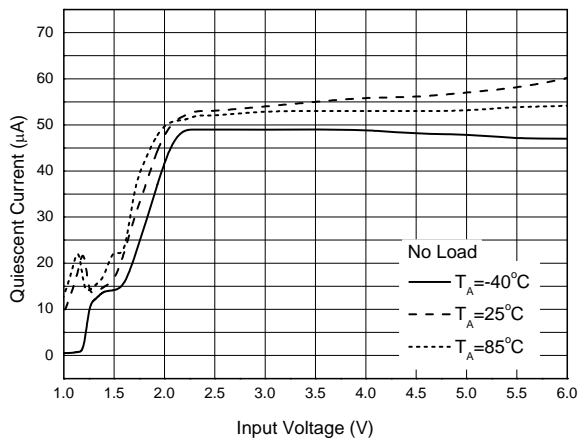


Figure 9. Quiescent Current vs. Input Voltage

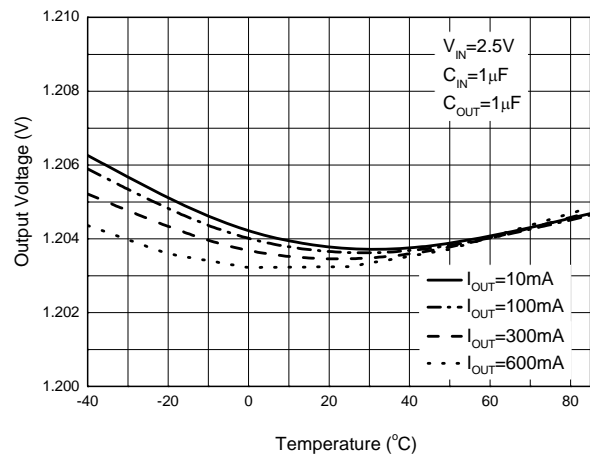


Figure 10. Output Voltage vs. Temperature

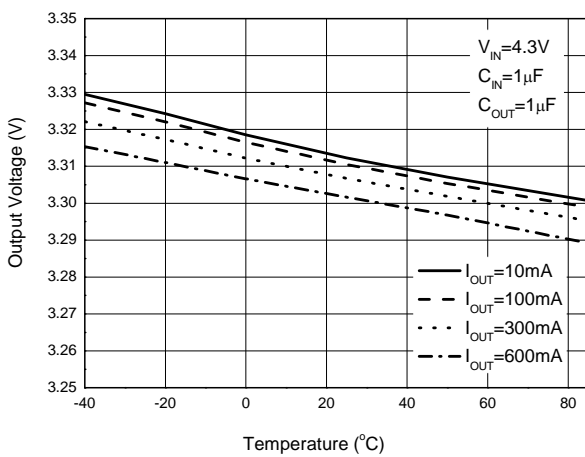


Figure 11. Output Voltage vs. Temperature

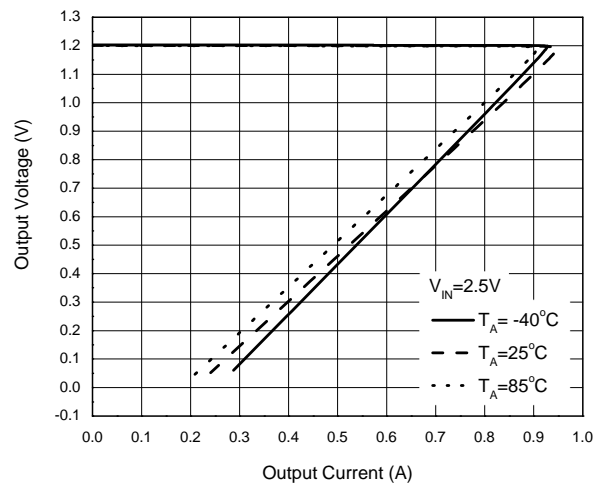


Figure 12. Output Voltage vs. Output Current

**Typical Performance Characteristics (Continued)**

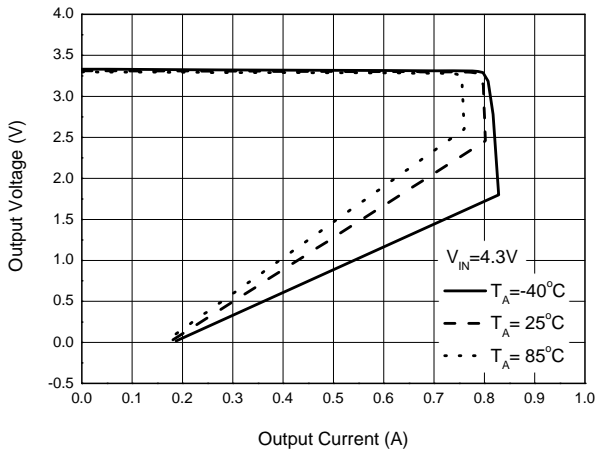


Figure 13. Output Voltage vs. Output Current

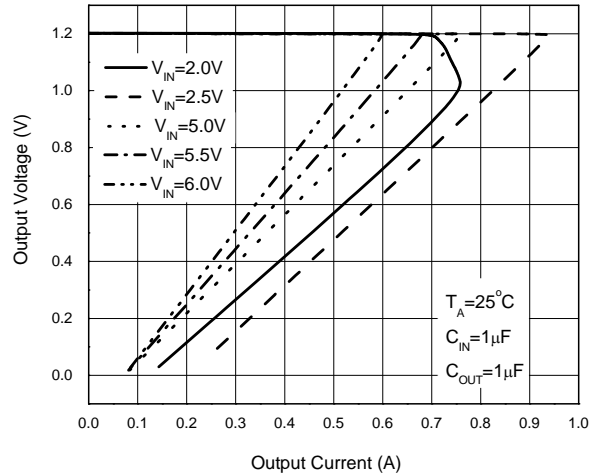


Figure 14. Output Voltage vs. Output Current

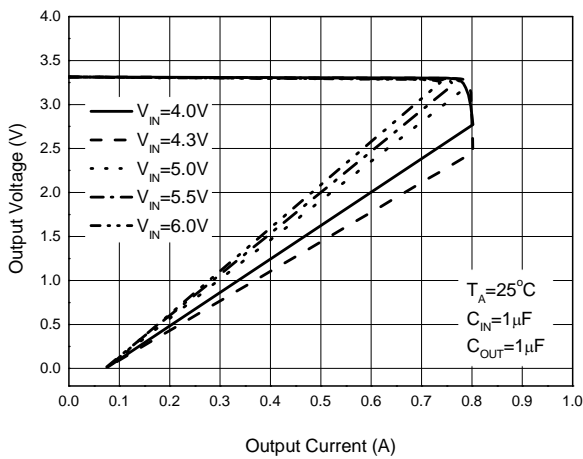


Figure 15. Output Voltage vs. Output Current

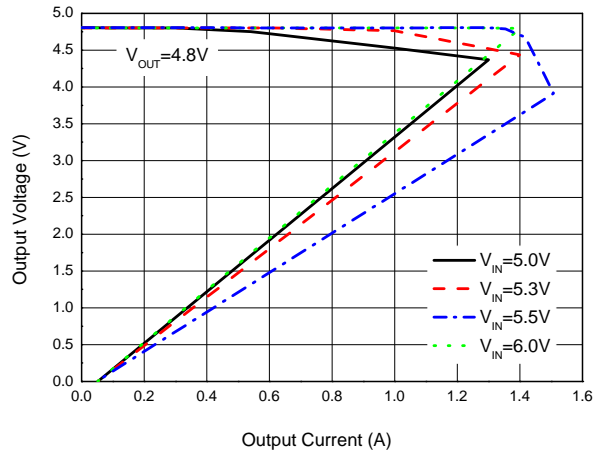


Figure 16. Output Voltage vs. Output Current



**Typical Performance Characteristics (Continued)**

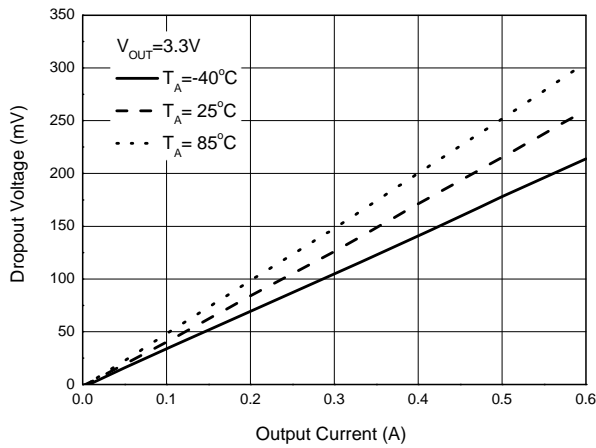


Figure 17. Dropout Voltage vs. Output Current

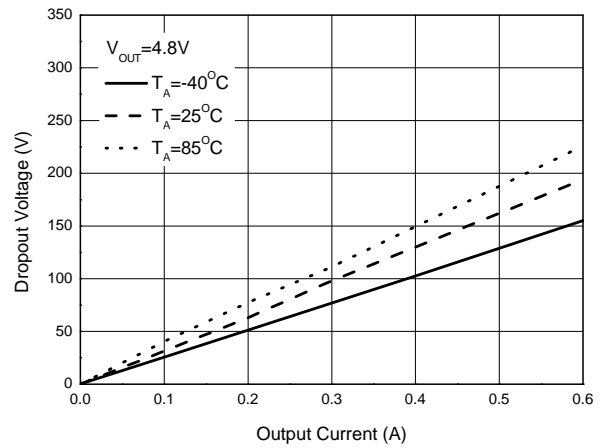


Figure 18. Dropout Voltage vs. Output Current

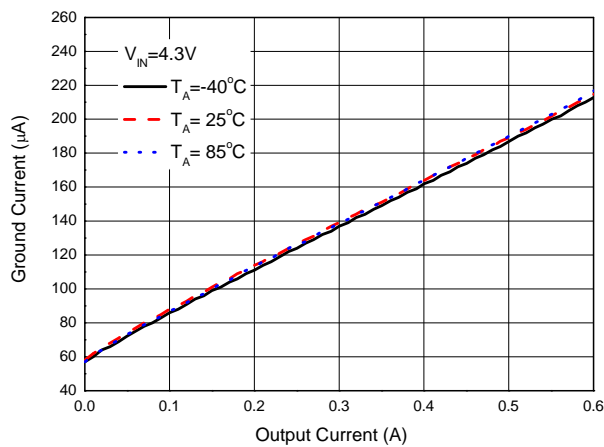


Figure 19. Ground Current vs. Output Current

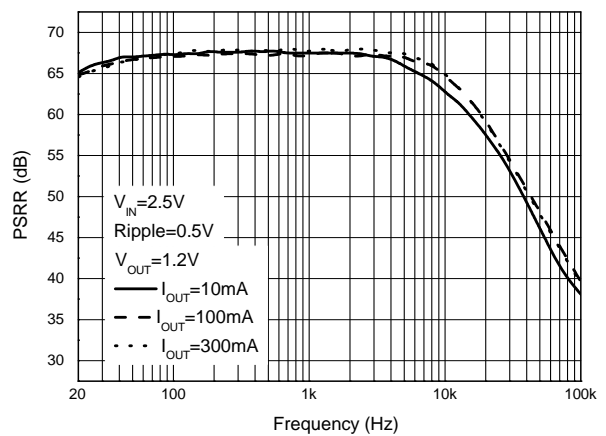


Figure 20. PSRR vs. Frequency

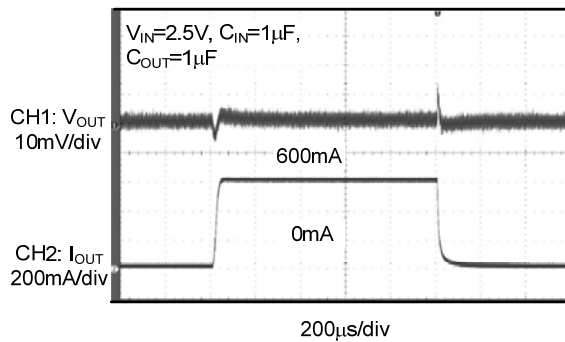
**Typical Performance Characteristics (Continued)**


Figure 21. Load Transient

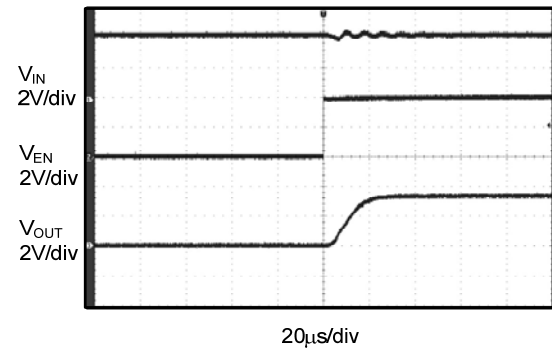


Figure 22. Enable On

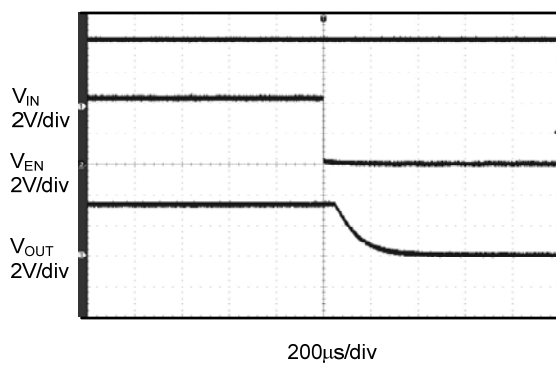
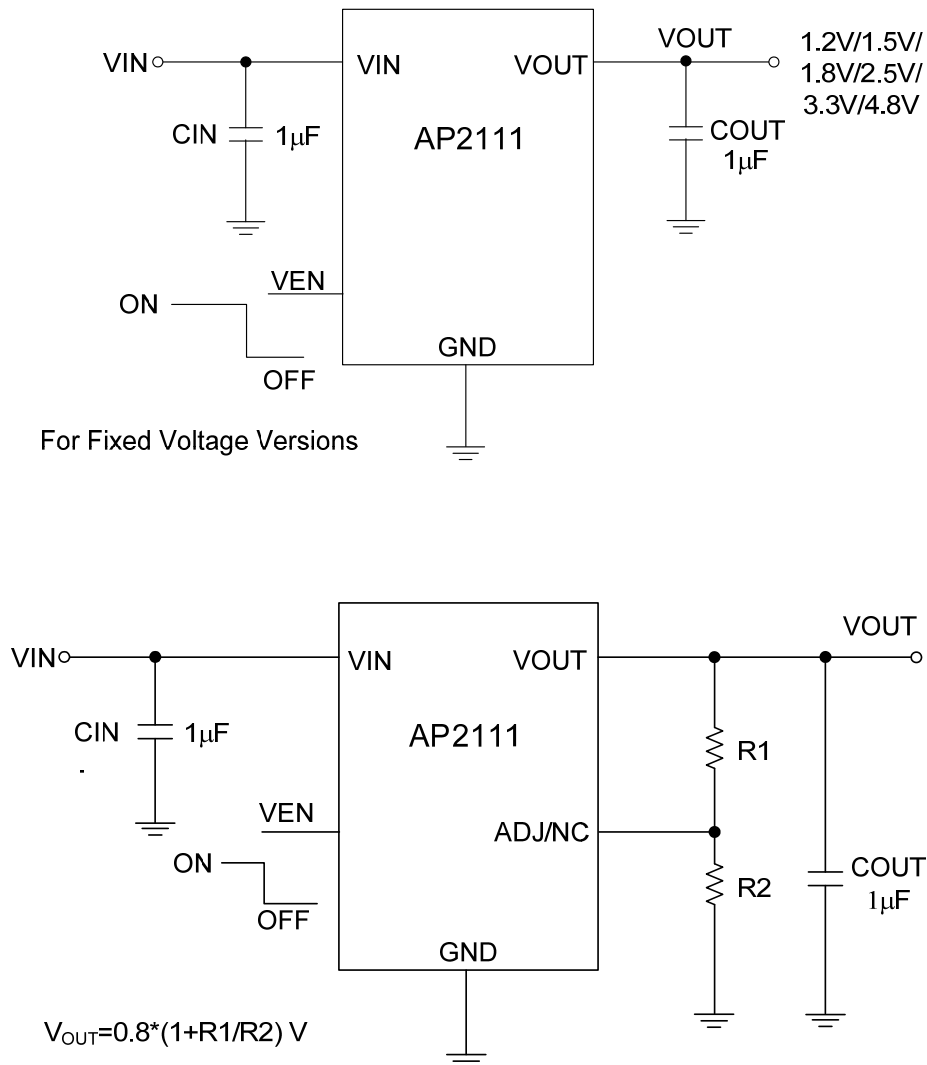
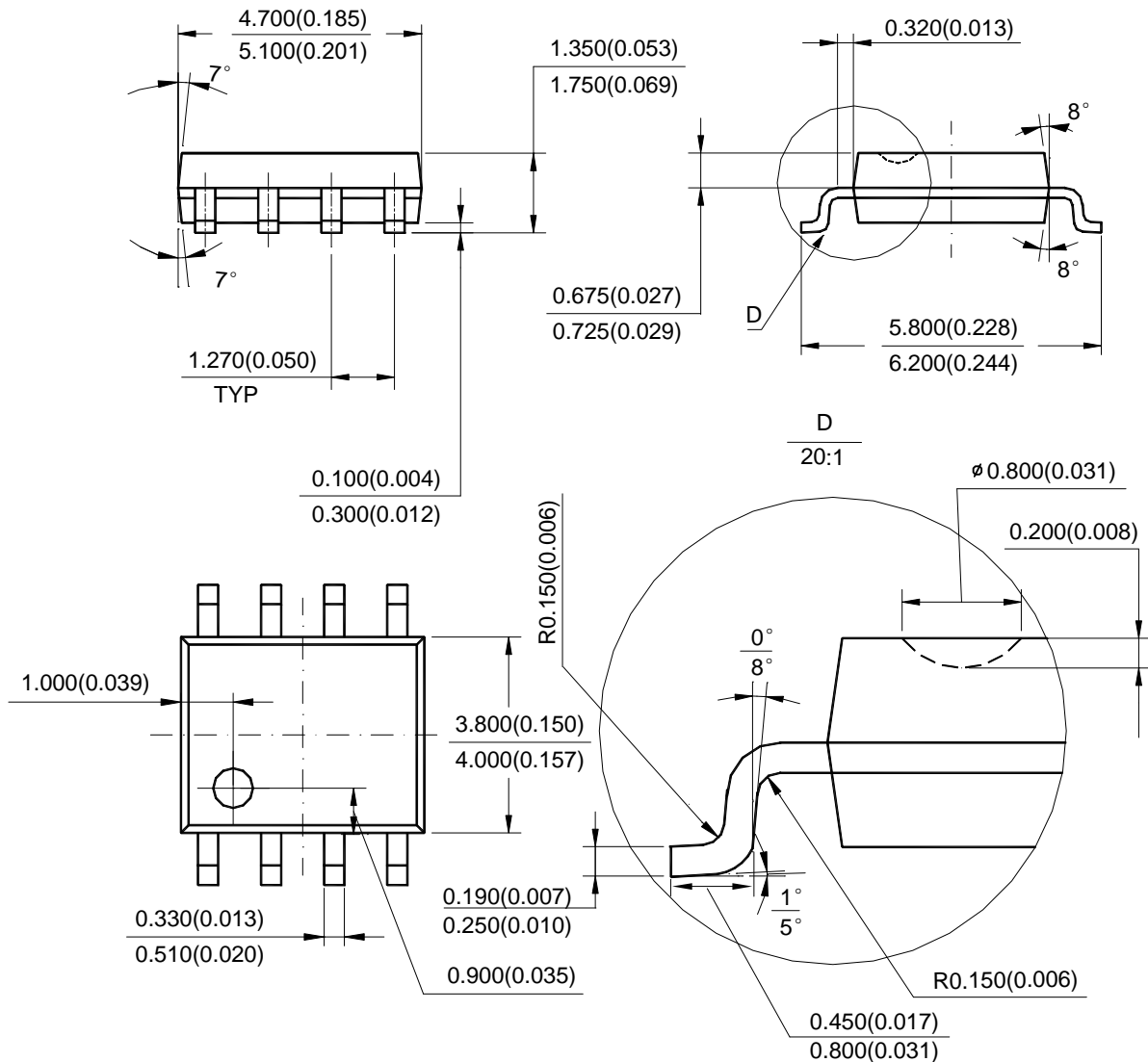


Figure 23. Enable Off

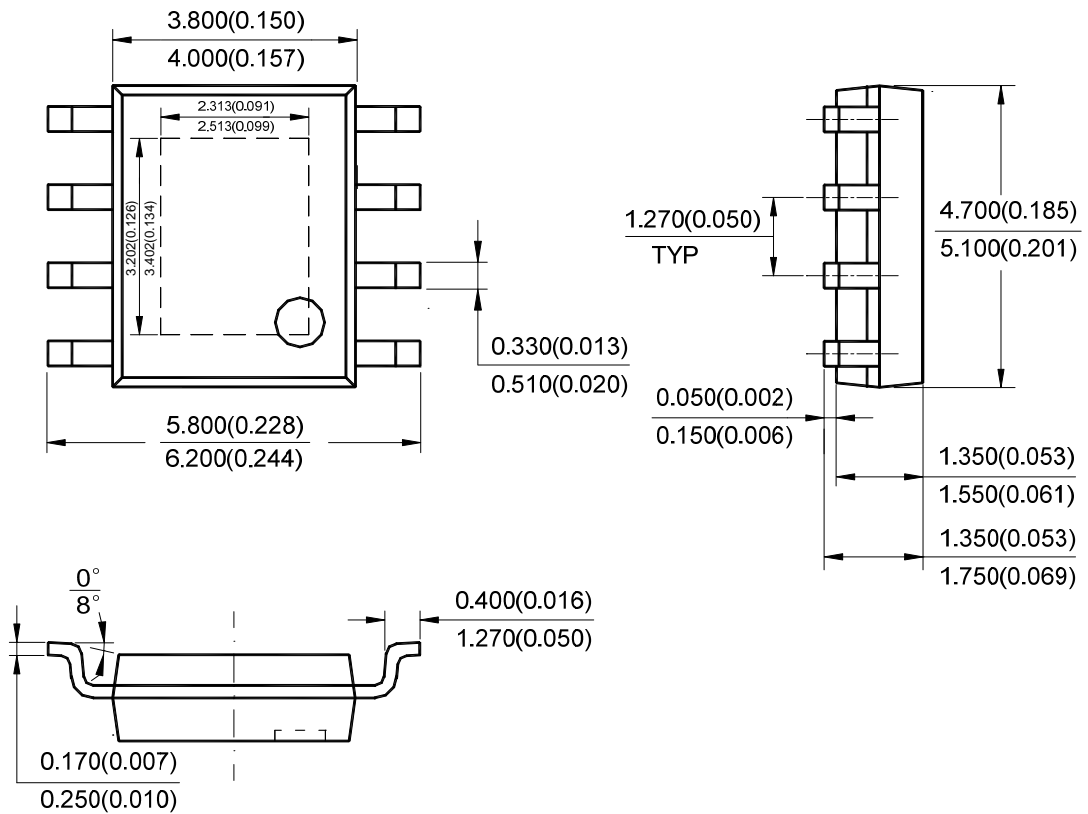
**Typical Application (Note 4)**


Note 4: It is recommended to use X7R or X5R dielectric capacitor if 1.0µF ceramic capacitor is selected as input/output capacitors.

Figure 24. Typical Application of AP2111

**Mechanical Dimensions****SOIC-8****Unit: mm(inch)**

Note: Eject hole, oriented hole and mold mark is optional.

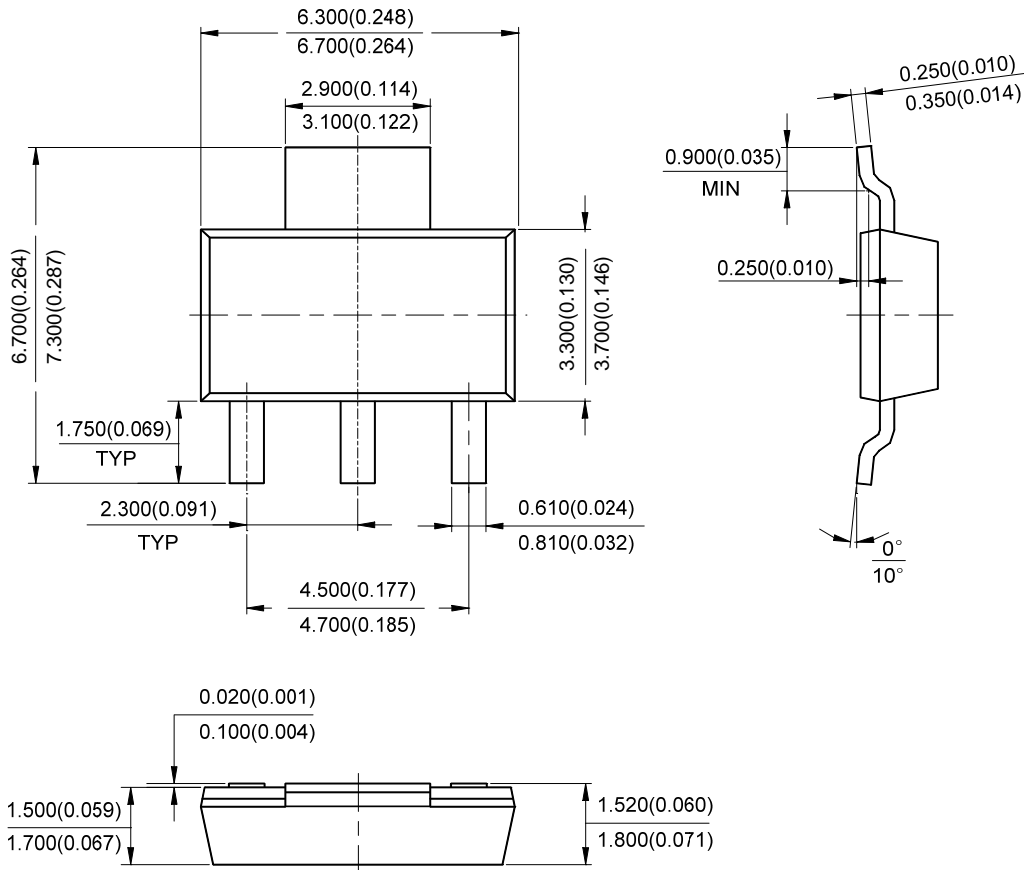
**Mechanical Dimensions (Continued)**
**PSOP-8**
**Unit: mm(inch)**


Note: Eject hole, oriented hole and mold mark is optional.

**Mechanical Dimensions (Continued)**

**SOT-223**

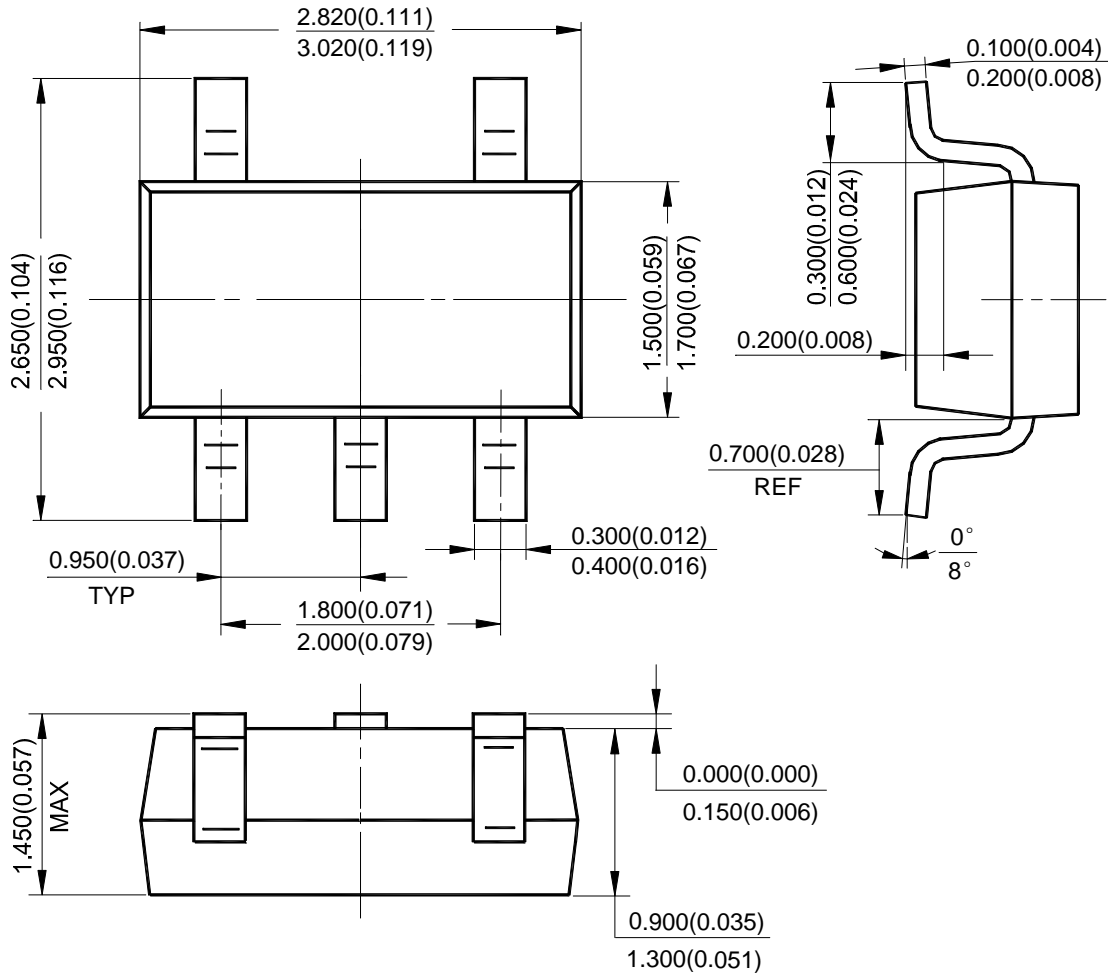
**Unit: mm(inch)**



**Mechanical Dimensions (Continued)**

**SOT-23-5**

**Unit: mm(inch)**





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